

Influence of Long-Range Coulomb Forces and Dissipation on the Persistent Current of a Wigner Crystal-Ring

I. V. Krive^(1,2), P. Sandström⁽¹⁾, R. I. Shekhter⁽¹⁾, and M. Jonson⁽¹⁾

⁽¹⁾*Department of Applied Physics, Chalmers University of Technology and Göteborg University,
S-412 96 Göteborg, Sweden*

⁽²⁾*B. I. Verkin Institute for Low Temperature Physics and Engineering, 47 Lenin Avenue, 310164
Kharkov, Ukraine*

Abstract

The influence of long-range Coulomb forces on the persistent current of a pinned Wigner crystal-ring is considered. A simple method is proposed for how to take into account Coulomb effects for the macroscopic quantum tunneling of the Wigner crystal. It is shown that unscreened Coulomb interactions increase the stiffness of the Wigner lattice. This leads to additional suppression of the amplitude of Aharonov-Bohm oscillations, but makes the predicted anomalous temperature dependence of the persistent current more pronounced. The impact of dissipation on the persistent current of a Wigner crystal-ring is also studied.

In condensed matter the Aharonov-Bohm effect manifests itself through magnetic oscillations of thermodynamic and kinetic properties of nonsimply connected mesoscopic systems. It is a well-known fact that the period of mesoscopic Aharonov-Bohm oscillations is equal to the flux quantum $\Phi_0 = hc/e$ (e is the electron charge) and that the oscillation amplitude depends on the properties (conductivity) of the system.

Until recently the main theoretical and experimental efforts were directed towards investigating conductance oscillations in small-sized metallic wires and rings (see e.g. the review [1]). Successful measurements of the flux-induced magnetic moment (persistent current) of isolated single metallic- [2] and semiconductor [3] rings have made the study of thermodynamic properties of mesoscopic quantum rings a central problem of considerable current interest. Whereas for metallic rings the problem at hand amounts to properly taking into account the effect of impurities on the persistent current of non- (or weakly) interacting electrons, the main goal in the case of semiconductor rings — formed in a laterally confined high mobility two-dimensional electron gas (2DEG) — is to elucidate the role of electron-electron correlations in the Aharonov-Bohm oscillations.

We recall [4] that in a perfect (impurity free) ring even strong Coulomb correlations do not influence the persistent current, which is the same as if calculated in the naive model of free electrons [5, 6]. This result can be proved as a theorem for Gallilean invariant systems (at zero temperature) [7]. In lattice models a drastic change in the magnitude of the persistent current comes about only in the vicinity of a metal-insulator phase transition induced by electron-electron correlations. In the latter case the oscillation amplitude becomes exponentially small [8,9,10], which is a characteristic feature of the Aharonov-Bohm effect in dielectrics [11, 12].

It is reasonable to study the quantum dynamics of electrons in one-dimensional (1D) channels — formed in a 2DEG by a smooth electrostatic potential — in the framework of continuum models. In this case Coulomb correlations favor the formation of an ordered structure at low density and temperatures. Such a Wigner crystal can exist in rings of large enough (mesoscopic) sizes [13]. A simple model of a 1D Wigner crystal has been suggested in

Ref. [14] and has proven to be suitable for studying charge transport in strongly correlated electron systems. This model was used in Ref. [15] for an evaluation of the persistent current in a ring-shaped Wigner crystal. It was demonstrated that in a perfect ring the persistent current caused by the sliding of a Wigner crystal is indistinguishable from the current carried by free electrons. The situation is drastically changed in the presence of even a small potential barrier. The barrier pins the crystal and charge transport is possible only due to the processes of thermal or quantum depinning. At low temperatures the latter is dominant and the current becomes of the tunneling type.

For strong pinning both the zero temperature value and the temperature dependence of the oscillation amplitude are significantly changed. An increase in temperature favours depinning of the crystal; hence at low temperatures $T \lesssim T_s \equiv \hbar s/L$ the current increases with temperature (s is the sound velocity in the Wigner lattice, L is the circumference of the ring). However, in the high temperature region ($T > T_s$) the persistent current is strongly (exponentially) suppressed due a temperature enhancement of destructive interference effects (loss of quantum coherence). Thus we get an anomalous temperature behaviour of the Aharonov-Bohm oscillations in a pinned Wigner crystal-ring that contradicts the prediction of Fermi-liquid theory [6] and is specific for strongly correlated electrons.

The above mentioned results were obtained in Ref. [15] for a simple model of a Wigner crystal without long-range Coulomb interactions and without effects of (possible) dissipative motion of the Wigner lattice. The purpose of the present paper is to estimate the influence of unscreened Coulomb forces and dissipation on the persistent current of a pinned Wigner crystal-ring.

A 1D Wigner crystal pinned by a potential V_p — local on the scale of the system size L — is described by the Lagrangian

$$\mathcal{L} = \frac{ma}{8\pi^2} \left\{ \dot{\varphi}^2 - s^2(\varphi')^2 \right\} - V_p \delta(x)(1 - \cos \varphi) + \frac{\hbar}{L} \frac{\Phi}{\Phi_0} \dot{\varphi} \quad (1)$$

Here a is the Wigner lattice spacing ($a^{-1} \equiv n$, n being the electron density), m is the electron mass, s is the sound velocity (the velocity of charged excitations - plasmons in the

Wigner crystal), $\varphi \equiv 2\pi u(x, t)/a$ stands for the dimensionless displacement field. The last term in Eq.(1) describes the Aharonov-Bohm interaction of the Wigner crystal with the magnetic flux Φ . It is worth noticing that the Lagrangian (1) is identical with the bosonized form of the Luttinger model (for spinless electrons) if one identifies the parameter η_ρ , which specifies the exponents of different correlation functions in the Luttinger model (see e.g. Ref. [16]), with the quantity $\alpha \equiv \pi\hbar/msa$ of our model. The parameter α determines the “strength” of quantum fluctuations in the system and in what follows it is assumed to be small $\alpha \ll 1$ (corresponding to a stiff Wigner crystal).

The long-range part of the Coulomb interaction is described by a standard expression, which in terms of the displacement field φ looks as follows [17] (see also [18])

$$E_c = \frac{e^2}{8\pi^2} \int \int dx dx' \frac{\partial_x \varphi(x) \partial_{x'} \varphi(x')}{\sqrt{(x - x')^2 + d^2}}. \quad (2)$$

Here d is the length associated with short wavelength “screening” (in fact the width of the one-mode channel). We will take it to be of the order of the Wigner crystal spacing $d \lesssim a$. In this case plasmons in the Wigner crystal ($ka \ll 1$) experience the influence of unscreened Coulomb forces and their dynamics are significantly changed.

In a constant-potential region the impact of Coulomb interactions, Eq.(2), on the dynamics of plasmons can be accounted for exactly (see e.g. Ref. [17])

$$\omega(k) = sk \left\{ 1 + \frac{2e^2}{mas^2} K_0(ka) \right\}^{1/2} \stackrel{(ka \ll 1)}{\approx} s_0 k \sqrt{\ln(1/ka)}, \quad (3)$$

where $K_0(x)$ is the MacDonald function, $s_0^2 \equiv 2e^2/ma$.

Our prime interest is in the question of how the Coulomb interaction, Eq.(2), influences the tunneling dynamics of a pinned Wigner crystal-ring. We will assume that the circumference of the ring is large enough, $L \gg a$, so that the Coulomb interaction becomes essential on scales for which one can neglect the effects of curvature (the distinction between ring-like and linear geometry).

It is physically evident that the main effect of the long-range Coulomb forces is connected with the change in the dispersion relation for plasmons, Eq.(3). How will this modification

influence the tunneling dynamics of a Wigner crystal-ring? It is obvious that Coulomb interactions affect the tunneling of the Wigner crystal through the barrier if it is accompanied by a distortion of the crystal so that $\varphi' \neq 0$. As was shown in Ref. [19], the tunneling process is inhomogeneous in the strong pinning regime (in our notations $\alpha_0 V_p \gg T_s$, where $T_s \equiv \hbar s_0/L$, $\alpha_0 \equiv \pi \hbar / m a s_0 \simeq \sqrt{a_B/a}$, $a_B \equiv \hbar^2/e^2 m$ being the Bohr radius). In this case the process of depinning the Wigner crystal can be divided into two different stages. In the first stage, the field φ rapidly changes its value, $\Delta\varphi = \pm 2\pi$, in the region $l_0 \simeq a m s_0^2/V_p \ll L$ that contains the barrier. The second stage describes a slow relaxation of the elastic deformation that is a result of the first stage; the relaxation is associated with propagation of plasmons. It is this second stage that dominates the action in the strong-pinning limit and in our case it is modified by the long-range forces.

The instanton describing the tunneling relaxation is the solution of a free equation of motion (in imaginary time τ) of the form

$$\ddot{\varphi} + s^2 \varphi'' + \frac{e^2}{ma} \partial_x \left\{ \int_{-L/2}^{L/2} dy \frac{\partial_y \varphi(y, \tau)}{\sqrt{(x-y)^2 + a^2}} \right\} = 0 \quad (4)$$

For a screened Coulomb interaction the desired solution is of the form [19] $\varphi = \pm 2 \arctan(s\tau/|x|)$. It is easy to show that for $x \sim s\tau \gg a$ the last term in Eq.(4) can be represented in a local form and the modified Larkin-Lee instanton, φ_{L-L} , obeys the equation

$$\ddot{\varphi}_{L-L} + s_0^2 \ln \left(\frac{|x|}{a} \right) \varphi_{L-L}'' = 0, \quad |x| \gg a. \quad (5)$$

(Recall that we placed the barrier at the point $x_0 = 0$). Thus our problem is reduced to the one solved by Larkin and Lee [19], but now with an x -dependent velocity $s(x) = s_0 \sqrt{\ln(|x|/a)}$. Since $s(x)$ is a smooth function, $|s'(x)/s(x)| \ll 1$, we readily get the desired instanton solution

$$\varphi_{L-L}(x, \tau) = \pm 2 \arctan \left(\sqrt{\ln \left(\frac{|x|}{a} \right) \frac{s_0 \tau}{|x|}} \right) \quad (6)$$

For the tunneling action corresponding to the trajectory (6) we find (see also [14])

$$A_t = \frac{\hbar}{\alpha_0} \frac{2}{3} \left\{ \ln^{3/2} \left(\frac{L}{a} \right) - \ln^{3/2} \left(\frac{l_0}{a} \right) \right\}. \quad (7)$$

The criterion of strong pinning implies that $V_p \gg e^2/L$. It is reasonable to assume that the renormalized barrier height — renormalized by short wavelength fluctuations — obeys the inequality $V_p < e^2/a$. Then the persistent current at zero temperature takes the form

$$I_{WC}(T=0) \sim (-1)^N \frac{eT_s}{\hbar} \left(\frac{e^2}{LV_p} \right)^{\frac{\sqrt{\ln N}}{\alpha_0}} \sin \left(2\pi \frac{\Phi}{\Phi_0} \right), \quad (8)$$

where nonessential prefactors have been omitted and N is the total number of electrons in the ring. The appearance of the additional factor $\sqrt{\ln N} > 1$ in the exponent in Eq.(8), can easily be understood from the scaling procedure

$$s \rightarrow s_0 \ln^{1/2} \left(\frac{L}{a} \right), \quad \alpha^{-1} \sim mas \rightarrow \alpha_0^{-1} \ln^{1/2}(N). \quad (9)$$

Now we consider the temperature behaviour of the persistent current. For a screened Coulomb interaction this problem has been studied in Ref. [15]. The trick described above (the replacement $s \rightarrow s(x) = s_0 \sqrt{\ln(|x|/a)}$) permits us to use the results of Ref. [15] and readily get the solution. At finite temperature the extremal trajectory is described by the function [15]

$$\varphi_\beta(x, \tau) = \pm 2 \arctan \left\{ \coth \left[\frac{\pi|x|}{\hbar\beta s(x)} \right] \tan \left[\frac{\pi}{\hbar\beta} \left(\tau - \frac{\hbar\beta}{2} \right) \right] \right\}, \quad (10)$$

where $\beta \equiv T^{-1}$ is the inverse temperature. The tunneling action corresponding to the periodic instanton (10) is

$$A_t(\tau) = \frac{\hbar}{\alpha_0} \int_{\pi \frac{T}{T_i}}^{\pi \frac{T}{T_s}} dx \left\{ \coth \left[\frac{x}{\sqrt{\ln(\frac{T_c}{T}x)}} \right] + \tanh \left[\frac{x}{\sqrt{\ln(\frac{T_c}{T}x)}} \right] - 1 \right\}, \quad (11)$$

where $T_i \equiv \hbar s_0/l_0$, $T_c \equiv \hbar s_0/a$. As a function of temperature, the action (11) attains its minimum at

$$T_M \simeq 0.5 T_s \sqrt{\ln N}, \quad A_t(T_M) \simeq \frac{\sqrt{\ln N}}{\alpha_0}, \quad (12)$$

which leads to the anomalous temperature dependence of the amplitude of the Aharonov-Bohm oscillations (see Fig.1).

Hence, the unscreened Coulomb interaction results in additional suppression of the persistent current of a strongly pinned Wigner crystal-ring. The peak in the current plotted as a function of temperature therefore becomes more pronounced. These results are consistent with the fact that long-range Coulomb interactions, by suppressing the quantum fluctuations of a Wigner crystal, transform it into an almost classical system $\alpha_0^{-1}\sqrt{\ln N} \rightarrow \infty$ as $N \rightarrow \infty$.

Now we proceed to the next question. How does dissipation influence the persistent current of a Wigner crystal-ring? The first problem is to introduce dissipation in our model Lagrangian, Eq.(1). Here we will use a phenomenological approach and consider the simplest model of dissipative motion, namely linear friction. In other words we will assume that due to the presumably weak coupling of electrons in the ring with the reservoir, the motion of a Wigner crystal becomes dissipative and can be described in terms of friction in a real time formalism. In such an approach it is reasonable to consider the friction as homogenous and local. Then for homogenous translations of the Wigner lattice, the dissipative equation of motion in real time looks as follows

$$m\ddot{\varphi} + \eta\dot{\varphi} = 0. \quad (13)$$

Here m is the electron mass and η is the friction coefficient. This equation, in essence, determines the normalization of the phenomenological parameter η .

To include friction in the tunneling dynamics, where imaginary time is more appropriate, we will follow the standard approach by Caldeira and Legget [20]. According to them linear friction in imaginary time, τ , can be described by the nonlocal action

$$A_{C-L} \sim \eta \int_0^\beta \int_0^\beta d\tau d\tau' \frac{[\varphi(\tau) - \varphi(\tau')]^2}{\frac{\beta^2}{\pi^2} \sin^2[\frac{\pi}{\beta}(\tau - \tau')]}. \quad (14)$$

Notice, however, that in our model the trajectories in imaginary time which differ from each other by $2\pi n$ (n is an integer) are physically indistinguishable. Therefore the action (14) should be slightly modified in order to account for the 2π -symmetry of the model, Eq.(1). We propose a dissipative action of the form

$$A_d = \frac{a\eta}{4\pi^3} \int_{-L/2}^{L/2} dx \int_0^\beta \int_0^\beta d\tau d\tau' \frac{\sin^2 \left[\frac{\varphi(x,\tau) - \varphi(x,\tau')}{2} \right]}{\frac{\beta^2}{\pi^2} \sin^2 \left[\frac{\pi}{\beta} (\tau - \tau') \right]}, \quad (15)$$

which leads to the desired form (13) of the equation of motion in real time. It furthermore respects the 2π -symmetry of the quantum dynamics of the system in question. It is worth noting that the dissipative action (15) is analogous to the one used repeatedly in superconductivity for describing the dissipative dynamics of Josephson junctions (see e.g. the review [21]).

For the nonlinear and nonlocal action, Eqs. (1) and (14), we failed to find an exact instanton solution. Therefore, in what follows we will restrict ourselves to the case of weak dissipation, where a perturbative analysis can be made. It is obvious that the opposite limit, the overdamped tunneling “motion” of the Wigner crystal, is described by the trajectories with zero winding number ($n = 0$) and the Aharonov-Bohm oscillations vanish.

At first we consider the case of a weakly pinned Wigner crystal, $\alpha V_p \ll T_s$, when the use of perturbation theory can be easily justified. For a weakly pinned Wigner crystal which tunnels through the impurity homogeneously, it is convenient to treat it as an effective particle of mass $M = Nm$ (N is the total number of electrons in the ring) when calculating the tunneling action. The characteristic time of tunneling, τ_* , through the barrier in this particular case is much smaller than the periods of time between successive tunneling events, $\tau_* = a\sqrt{M/2V_p} \ll \beta$ [15] and since the effects of dissipation manifest itself most significantly on large time scales ($\sim \beta$), one can reliably use perturbation theory.

Substituting unperturbed tunneling trajectories $\varphi(\tau) = 2\pi\tau/\tau_*$, $\tau \in [-\tau_*/2, \tau_*/2]$ into Eqs.(1) and (15) one finds

$$A_t = \sqrt{2\pi \frac{V_p}{T_0}} + 0.3 \frac{\hbar\gamma}{T_0}, \quad (16)$$

where the first term represents the tunneling action in the dissipationless regime, $T_0 \equiv \hbar v_F/L$ ($V_p \gtrsim T_0$), and the dissipative correction ($\gamma \equiv \eta/2m$, $\hbar\gamma \ll T_* \simeq \sqrt{V_p T_0}$) can be interpreted as being due to the broadening of the quantized levels of the system.

In the dilute instanton gas approximation ($A_t \gg 1$) the amplitude of the persistent cur-

rent is proportional to $\exp(-A_t)$. Hence dissipation exponentially suppresses the Aharonov-Bohm oscillations (as it should, see also [22, 12]). Notice that Eq.(16) is valid up to the crossover temperature $T_* \simeq \sqrt{V_p T_0}$ (temperature corrections are of the order T/T_*). Therefore the criterion for the perturbation expansion to be valid, $\hbar\gamma \ll T_*$, does not have to be violated in the case of moderately weak pinning ($V_p \gtrsim T_0 \rightarrow T_* \gtrsim T_0$) even if dissipation is strong (in terms of free electrons) $\hbar\gamma \gtrsim T_0$. The dissipation, of course, remains weak for plasmons $\hbar\gamma \ll T_s$.

In the regime of strong pinning, $\alpha V_p \gg T_s$, the tunneling of a Wigner crystal is inhomogeneous and the characteristic tunneling time is of the order of L/s . In this case one would expect a stronger influence of dissipation on tunneling. However, it is easy to show that for a stiff ($\alpha \ll 1$) crystal, the impact of dissipation on the persistent current is similar to the case described above. By substituting Eq.(9) into Eq.(15) and doing the integrals one can readily get the simple result

$$\Delta A_t = \frac{1}{2} \frac{\hbar\gamma}{T_0}. \quad (17)$$

Again the perturbative correction due to dissipation does not depend on temperature or barrier height. This expression exactly coincides with the dissipative action for an elementary transition ($\Delta\varphi = \pm 2\pi, n = \pm 1$) of a perfect Wigner crystal

$$A_t = \frac{\pi}{2} \frac{T}{T_0} n^2 + \frac{1}{2} \frac{\hbar\gamma}{T_0} |n| \quad (18)$$

This result can easily be obtained from Eqs.(1) and (15), by making use of the extremal trajectories $\varphi_n = 2\pi n\tau/\beta$ for a perfect Wigner crystal-ring. One can see from Eq.(18) that dissipative corrections are small at temperatures $T \gg \hbar\gamma$. Therefore in the high temperature region the impact of dissipation on the persistent current — even for a perfect Wigner crystal — can be accounted for perturbatively. The presence of a barrier results in the appearance of a new energy scale and this enables us to use perturbation theory even at $T \rightarrow 0$.

Thus, in all cases considered, the dissipative corrections to the persistent current factorize as an overall factor, $\exp(-\text{const } \hbar\gamma/T_0)$. They depend neither on temperature nor on

the strength of the pinning potential (we assume that $V_p \gtrsim \hbar v_F/L$). This implies that dissipation, even if the ring is strongly connected to reservoirs ($\hbar\gamma \sim \hbar v_F/L$), though it suppresses the current, does not change the anomalous temperature behaviour predicted in Ref. [15].

This work was supported by the Swedish Royal Academy of Sciences, the Swedish Natural Science Research Council, and by grant U2K000 from the International Science Foundation. One of us (I.K.) acknowledges the hospitality of the Department of Applied Physics, CTH/GU.

REFERENCES

- [1] S. Washburn, and R. A. Webb, *Repts. Progr. Phys.* **55**, 1311 (1992);
- [2] V. Chandrasekhar, R. A. Webb, M. J. Brady, M. B. Ketchen, W. J. Gallagher, and A. Kleinsasser, *Phys. Rev. Lett.* **67**, 3578 (1991).
- [3] D. Mailly, C. Chapelier, and A. Benoit, *Phys. Rev. Lett.* **70**, 2020 (1993).
- [4] D. Loss, *Phys. Rev. Lett.* **69**, 343 (1992).
- [5] I. O. Kulik, *JETP Lett.* **11**, 275 (1970).
- [6] H.-F. Cheung, Y. Gefen, E. K. Riedel, and W.-H. Shih, *Phys. Rev.* **B37**, 6050 (1988).
- [7] A. Müller-Groeling, H. A. Weidenmüller, and C. H. Lewenkopf, *Europhys. Lett.* **22**, 193 (1993).
- [8] B. S. Shastry, and B. Sutherland, *Phys. Rev. Lett.* **65**, 243 (1990).
- [9] C. A. Stafford, and A. J. Millis, *Phys. Rev.* **B48**, 1409 (1993).
- [10] M. Abraham, and R. Berkovits, *Phys. Rev. Lett.* **70**, 1509 (1993).
- [11] I. O. Kulik, A. S. Rozhavsky, and E. N. Bogachek, *JETP Lett.* **47**, 303 (1988).
E. N. Bogachek, I. V. Krive, I. O. Kulik, and A. S. Rozhavsky, *Phys. Rev.* **B42**, 7614 (1990).
- [12] I. V. Krive, and A. S. Rozhavsky, *Int. J. Mod. Phys.* **B6**, 1255 (1992).
- [13] D. V. Averin, and K. K. Likharev, In: *Mesoscopic Phenomena in Solids*,
Eds. B. Altshuler, P. A. Lee, and R. A. Webb (Elsevier, Amsterdam, 1991).
K. Jauregui, W. Häusler, and B. Kramer, *Europhys. Lett.* **24**, 581 (1993).
- [14] L. I. Glazman, I. M. Ruzin, and B. I. Shlovskii, *Phys. Rev.* **B45**, 8454 (1992).
- [15] I. V. Krive, R. I. Shekhter, S. M. Girvin, and M. Jonson, *Göteborg preprint* **APR 93-38**
(cond-mat/9404072); I. V. Krive, R. I. Shekhter, S. M. Girvin, and M. Jonson, *Göteborg*
preprint **APR 93-53**
- [16] A. Furusaki, and N. Nagaosa, *Phys. Rev.* **B47**, 3827 (1993).
- [17] H. J. Schulz, *Phys. Rev. Lett.* **71**, 1864 (1993);

- [18] M. Fabrizio, A. O. Gogolin, and S. Scheidl, *Phys. Rev. Lett.* **72**, 2235 (1994).
- [19] A. I. Larkin, and P. A. Lee, *Phys. Rev.* **B17**, 1596 (1978).
- [20] A. O. Caldeira, and A. J. Leggett, *Ann. Phys.* **149**, 374 (1983).
- [21] G. Schön, and A. D. Zaikin, *Phys. Repts.* **198**, 237 (1990).
- [22] M. Büttiker, *Phys. Rev.* **B32**, 1846 (1985).

FIGURE CAPTION

FIG.1. Temperature dependence of the normalized persistent current in a strongly pinned Wigner crystal for two different stiffnesses, α^{-1} , without long-range Coulomb forces (solid line) and when Coulomb forces are considered (dotted line). The Coulomb forces increase the effective stiffness of the Wigner lattice ($\alpha^{-1} \rightarrow \alpha_0^{-1} \sqrt{\ln N}$, N = the number of particles. Here $N = 100$) resulting in additional suppression of the persistent current. The peak in the current will therefore become more pronounced and the corresponding temperature will be shifted by a factor $\simeq \sqrt{\ln N}$. Note that the persistent current in all cases is normalized to its zero temperature value, which is smaller in the presence of long-range Coulomb forces (see text).